Bi-CMOS LSI

Multi-Power Supply IC for Car Audio Systems



http://onsemi.com

Overview

LV5686PVC is a multiple voltage regulator for Car Audio System. This IC has 3 voltage regulators, 5V output for a microcontroller, 9.85V output for illuminations, 9V output for audio control and 6 high side switches. About protection circuits, it has Over-current-protection, Over-voltage-protection and Thermal-shut-down. This IC is most suitable for Car Audio System.

Features

• 3 system regulators

VDD (MCU): VOUT 5V, IOUT max 300mA, reverse current prevention.

Illumination : V_{OUT} 9.85V, I_{OUT} max 300mA Audio : V_{OUT} 9.0V, I_{OUT} max 500mA

• 6 high side switches

AMP: IOUT max 300mA, voltage difference between input and output: 1.0V ANT: IOUT max 300mA, voltage difference between input and output: 1.0V EXT1: IOUT max 500mA, voltage difference between input and output: 1.0V EXT2: IOUT max 500mA, voltage difference between input and output: 1.0V EXT3: IOUT max 350mA, voltage difference between input and output: 0.5V EXT4: IOUT max 500mA, voltage difference between input and output: 1.0V

- Over Current Protection
- BATT. Detection: under voltage1 (<6.5V), under voltage2 (<9.5V) and over voltage (>18V)
- Over Voltage Protection Typ 25V (shutdown except VDD)
- Thermal Shut Down Circuit Typ 175°C
- Applied P-LDMOS to Output stage

(Warning) The protector functions only improve the IC's tolerance and they do not guarantee the safety of the IC if used under the conditions out of safety range or ratings. Use of the IC such as use under overcurrent protection range, thermal shutdown state or V6IN OVS condition may degrade the IC's reliability and eventually damage the IC.

Specifications

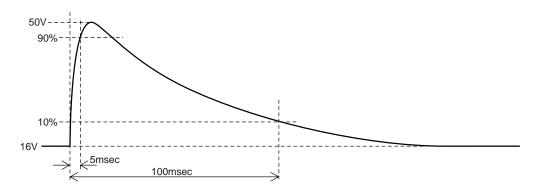
Absolute Maximum Ratings at Ta = 25°C

Parameter	Conditions	Conditions		Ratings	Unit
Maximum supply voltage	V _{CC} max			36	V
Allowable power dissipation	Pd max	Independent IC	Ta ≤ 25°C	1.3	W
		Al heat sink *		5.3	W
		With an infinity heat sink		26.0	W
Peak supply voltage	V _{CC} peak	See below for the waveform applied.		50	V
Operating ambient temperature	Topr			-40 to +85	°C
Storage temperature	Tstg			-55 to +150	°C
Junction temperature	Tj max			150	°C

^{* :} When the Aluminum heat sink (50mm \times 50mm \times 1.5mm) is used

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Waveform of surge test



Recommended Operating Range at Ta = 25°C

Parameter	Conditions	Ratings	Unit
Operating supply voltage 1	V _{DD} (5V)	6.5 to 16	V
Operating supply voltage 2	AUDIO(9V)	11.5 to 16	V
Operating supply voltage 3	ILM(9.85V)	12.5 to 16	V
Operating supply voltage 4	AMP, ANT, EXT1, EXT2, EXT3, EXT4	7.5 to 16	V

Electrical Characteristics (1) at Ta = 25 °C, $V_{CC} = 14.4$ V (*1)

Parameter	Symbol	Conditions		Ratings		Unit
i alametei	Зупівої	Conditions	min	typ	max	Offic
Quiescent current	Icc	V_{DD} No Load, EN/CTRL1/2 = $\lceil L/L/L \rfloor$		60	100	μΑ
EN (AUDIO, ILM, AMP, EXT	1 control)					
「L」input voltage	V _{IL} 1	All: OFF	0		0.3	V
「M」 input voltage	V _{IM} 1	AUDIO, ILM, EXT1: ON	1.1	1.65	2.1	V
「H」input voltage	V _{IM} 1	All: ON	2.7	3.3	5.5	V
Input impedance	R _{IN} 1	Input voltage ≤ 3.3V	280	400	520	kΩ
CTRL1 (EXT2, EXT4 control)					
「L」input voltage	V _{IL} 2	All: OFF	0		0.3	V
「M」 input voltage	V _{IM} 2	EXT2: ON	1.1	1.65	2.1	V
「H」input voltage	V _{IM} 2	All: ON	2.7	3.3	5.5	V
Input impedance	R _{IN} 2	Input voltage ≤ 3.3V	280	400	520	kΩ
CTRL2 (ANT, EXT3 control)	<u>.</u>	•		•		•
「L」input voltage	V _{IL} 3	All: OFF	0		0.3	V
「M」input voltage	V _{IM} 3	ANT: ON	1.1	1.65	2.1	V
「H」input voltage	V _{IM} 3	All: ON	2.7	3.3	5.5	V
Input impedance	R _{IN} 3	Input voltage ≤ 3.3V	280	400	520	kΩ
V _{DD} output 5V (reverse cur	rent prevention diode	e implemented)				
V _{DD} output voltage	V _O 1	I _O 1 = 200mA	4.75	5.0	5.25	V
V _{DD} output current	I _O 1	V _O 1 > 4.7V	300			mA
Line regulation	ΔV _{OLN} 1	7.5V < V _{CC} < 16V, I _O 1 = 200mA		30	60	mV
Load regulation	ΔV _{OLD} 1	1mA < I _O 1 < 200mA		70	140	mV
Dropout voltage	V _{DROP} 1	I _O 1 = 150mA		1.25	1.5	V
Ripple rejection	R _{REJ} 1	f = 120Hz, I _O 1 = 200mA	40	50		dB
V _{DD} reverse current	Irev	V _O 1 = 5V, V _{CC} = 0V		10	100	μΑ
ILM output 9.85V-ON ; EN =	= [M], [H]	•		•		•
ILM output voltage	V _O 2	I _O 2 = 200mA	9.36	9.85	10.34	V
ILM output current	I _O 2	V _O 2 > 9.2V 300			mA	
Line regulation	ΔV _{OLN} 2	12.5V < V _{CC} < 16V, I _O 2 = 200mA		30	60	mV
Load regulation	ΔV_{OLD}^2	1mA < I _O 2 < 200mA		70	140	mV
Dropout voltage	V _{DROP} 2	I _O 2 = 200mA		1.0	1.5	V
Ripple rejection	R _{REJ} 2	f = 120Hz, I _O 2 = 200mA	40	50		dB

^(*1) All the specification is defined based on the tests performed under the conditions where Tj and Ta(=25°C) are almost equal. These tests were performed with pulse load to minimize the increase of junction temperature (Tj).

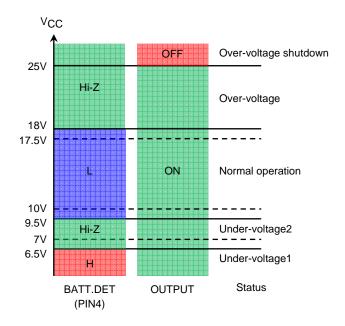
Electrical Characteristics (2) at Ta = 25 °C, $V_{CC} = 14.4$ V

D	O. made at	O and distance		Ratings		Unit
Parameter	Symbol	Symbol Conditions		typ	max	Offic
AUDIO output 9.0V -ON ; El	$N = \lceil M \rfloor, \lceil H \rfloor$	•				
AUDIO output voltage	V _O 3	I _O 3 = 400mA	8.55	9.0	9.45	V
AUDIO output current	I _O 3	V _O 3 > 8.5V	500			mA
Line regulation	ΔV _{OLN} 3	11.5V < V _{CC} < 16V, I _O 3 = 400mA		40	80	mV
Load regulation	ΔV _{OLD} 3	1mA < I _O 3 < 400mA		70	140	mV
Dropout voltage	V _{DROP} 3	I _O 3 = 200mA		0.6	1.0	V
Ripple rejection	R _{REJ} 3	f = 120Hz, I _O 3 = 200mA	45	60		dB
AMP Remote-ON; EN = H	J		<u> </u>		•	
Output voltage	V _O 4	I _O 4 = 300mA	V _{CC} -1.8	V _{CC} -1.0		V
Output current	I _O 4	V _O 4 ≥ V _{CC} -1.8	300			mA
ANT Remote-ON ; CTRL2 =	[M], [H]		<u> </u>		•	
Output voltage	V _O 5	I _O 5 = 300mA	V _{CC} -1.8	V _{CC} -1.0		V
Output current	I _O 5	V _O 5 ≥ V _{CC} -1.8	300			mA
EXT1-ON ; EN = [M], [H]		•				
Output voltage	V _O 6	I _O 6 = 500mA	V _{CC} -1.8	V _{CC} -1.0		V
Output current	I _O 6	V _O 6 ≥ V _{CC} -1.8	500			mA
EXT2-ON; CTRL1 = [M], [H	ı]		<u> </u>		•	
Output voltage	V _O 7	I _O 7 = 500mA	V _{CC} -1.8	V _{CC} -1.0		V
Output current	I _O 7	V _O 7 ≥ V _{CC} -1.8	500			mA
EXT3-ON; CTRL2 = [H]	•		<u> </u>		•	
Output voltage	V _O 8	I _O 8 = 350mA	V _{CC} -1.8	V _{CC} -1.0		V
Output current	I _O 8	V _O 8 ≥ V _{CC} -1.0	350			mA
EXT4-ON; CTRL1 = [H]	•			1		
Output voltage	V _O 9	I _O 9 = 500mA	V _{CC} -1.8	V _{CC} -1.0		V
Output current	I _O 9	V _O 9 ≥ V _{CC} -1.8	500			mA

Electrical Characteristics (3) at Ta = 25 °C, $V_{CC} = 14.4$ V

D	O:	Conditions		Ratings		Unit	
Parameter	Symbol	Conditions	min typ		max	Offic	
BATT.DET output: V _{CC} volta	ge detection						
BATT.DET output voltage	Voff	I _{OL} = 1mA, undetected.		0.3	0.4	V	
BATT.DET output voltage	Von	I _{OH} = -1mA, Under-voltage1	V _{DD} -0.4	V _{DD} -0.3		V	
Under-voltage detect threshold1	VthL1	V_{CC} falling, BATT.DET: "Hi-Z" \rightarrow "Hi"	6.3	6.5	6.7	V	
Under-voltage release threshold1	VthL1r	V _{CC} rising	6.8	7.0	7.2	V	
Under-voltage1 Hysteresis	Vuv1hys		0.4	0.5	0.6	V	
Under-voltage detect threshold2	VthL2	V_{CC} falling, BATT.DET: "Lo" \rightarrow "Hi-Z"	9.25	9.5	9.75	V	
Under-voltage release threshold2	VthL2r	V _{CC} rising	9.75	10	10.25	V	
Under-voltage2 Hysteresis	Vuv2hys		0.4	0.5	0.6	V	
Over-voltage detect threshold	VthH	V_{CC} rising, BATT.DET: "Lo" \rightarrow "Hi-Z"	17	18	19	V	
Over-voltage release threshold	VthHr	V _{CC} falling	16.5	17.5	18.5	V	
Over-voltage Hysteresis	Vovhys		0.4	0.5	0.6	V	
Overvoltage shutdown	Vovp	no hysteresis	22.5	25	27.5	V	

^{*}VCC voltage detection & over-voltage shutdown



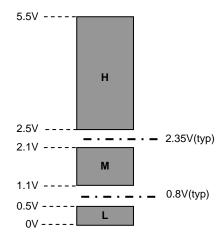
CTRL terminal truth table

• • • • •	0		10.0	
EN	EXT1	AUDIO	ILM	AMP
L	OFF	OFF	OFF	OFF
M	ON	ON	ON	OFF
Н	ON	ON	ON	ON

CTRL1	EXT2	EXT4
L	OFF	OFF
М	ON	OFF
Н	ON	ON

CTRL2	ANT	EXT3
L	OFF	OFF
М	ON	OFF
Н	ON	ON

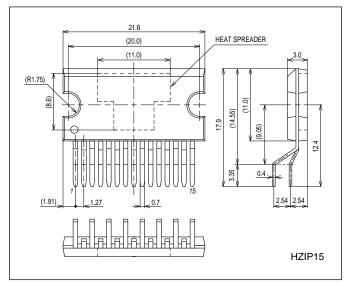
EN/CTRL1/CTRL2 voltage range and threshold



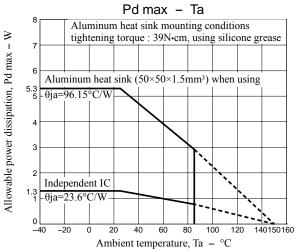
Package Dimensions

unit: mm (typ)

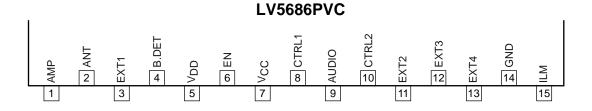
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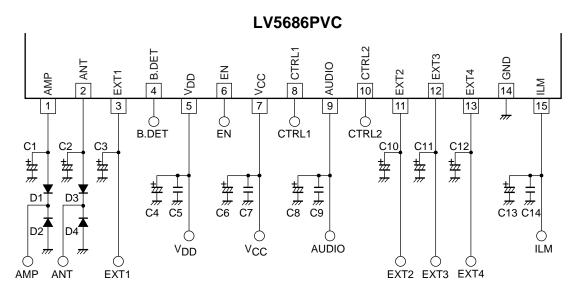
• Allowable power dissipation derating curve



Pin assignment



Application Circuit Example



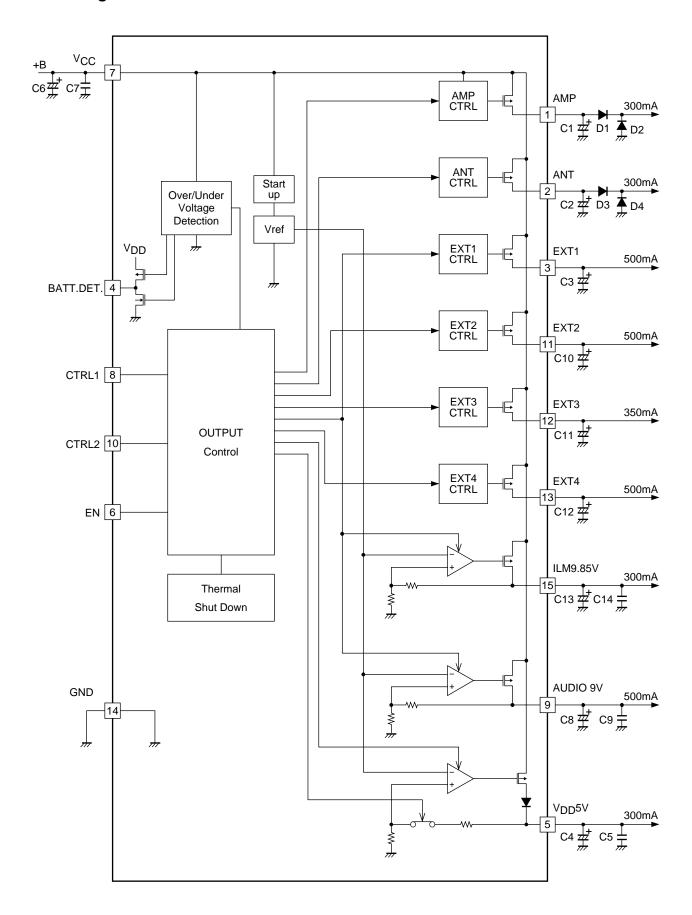
Peripheral parts

Part name	Description	Recommended value	Note
C1, C2, C3, C10, C11, C12	output stabilization capacitor for high-side switches	greater than 2.2μF	
C4, C8, C13	output stabilization capacitor	greater than10μF (*1)	
C5, C9, C14	output stabilization capacitor	greater than0.22μF (*1)	Ceramic capacitor
C6	Capacitor for bypass power supply	greater than 100μF	Make sure to implement close to
C7	Capacitor for oscillation protector	greater than 0.22μF	V _{CC} and GND.
D1, D2, D3, D4	Internal device protector diode	SB1003M3	(*2)

Note: Circuit diagram and the values are only tentative and subject to change.

- (*1) Make sure that total capacitance of regulator output is greater than $10\mu F$ and meets the condition of ESR = 0.001 to 10Ω , in which voltage/temperature dependence and unit differences are taken into consideration. Moreover, in case of electrolytic capacitor, high-frequency characteristics should be sufficiently good.
- (*2) These parts are necessary if output voltage of high-side switches gets lower than GND or higher than V_{CC}. The same consideration is required on EXT1 through EXT4.

Block Diagram



Pin Function

	Inction	T	1
Pin No.	Pin name	Description	Equivalent Circuit
1	AMP	AMP output When EN = H, AMP is ON V _{CC} -1V/300mA	7 \$\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\
			GND GND
2	ANT	ANT output When CTRL2 = M or H, ANT is ON VCC-1V/300mA	7 \$\\\ \\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\
			(14)——GND
3	EXT1	EXT1 output When EN = M or H, EXT1 is ON V _{CC} -1V/500mA	7 VCC \$100kΩ 3 W 5kΩ GND
4	BATT.DET	Battery voltage detector output L:9.5V <vcc<18v hiz:6.5v<vcc<9.5v="" or="" vcc="">18V H (VDD):VCC<6.5V</vcc<18v>	5 V _{DD} V _{DD} (4) (14) GND

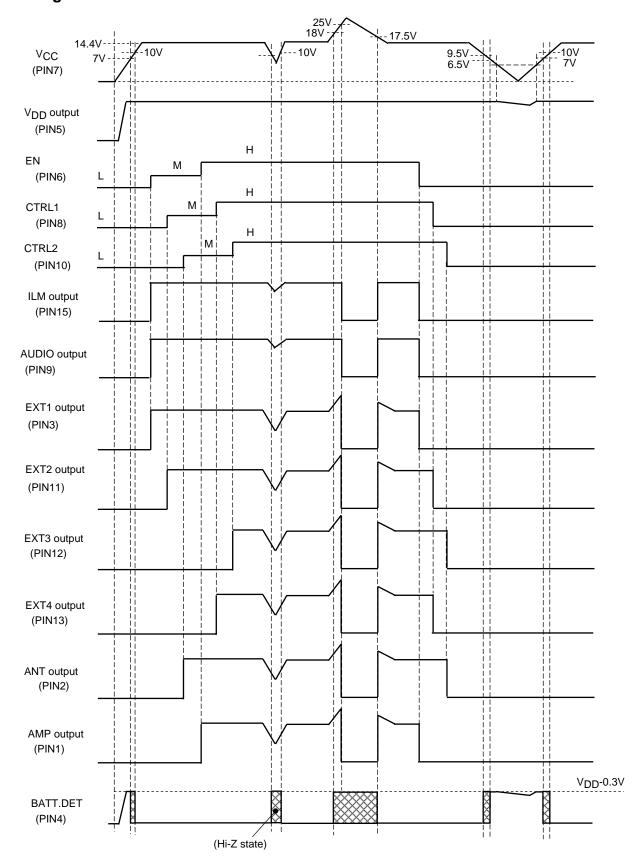
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Continued from preceding page. Pin No. Pin name Description Equivalent Circuit V_{DD} output, 5 V_{DD} Vcc 5.0V/0.3A ≸420kΩ ≱140kΩ (14) GND 6 ΕN Control input (7) Vcc CTRL1 8 3-value input 10 CTRL2 ≹10kΩ (8) (10) ≨140kΩ **≱**165kΩ ∄⊦ 0.5V ∫ ≸85kΩ (14) GND 7 V_{CC} Power supply (7)VCC 本 (14) -GND AUDIO AUDIO output 9 VCC When EN = M or H, AUDIO is ON 9V/0.5A (9) 279kΩ] Š 45kΩ (14) GND 11 EXT2 EXT2 output 7 VCC When CTRL1 = M or H, ≸100kΩ EXT2 is ON V_{CC}-1V/500mA (11) (14) GND

Continued on next page.

Pin No.	Pin name	Description	Equivalent Circuit
12	EXT3	EXT3 output When CTRL2 = H, EXT3 is ON VCC-0.5V/350mA	7 \$\frac{100kΩ}{5kΩ}\$\frac{100kΩ}{5kΩ}\$
13	EXT4	EXT4 output When CTRL1 = H, EXT4 is ON V _{CC} -1V/500mA	7 VCC \$100kΩ VCC \$100kΩ GND
14	GND		
15	ILM	ILM output When EN = M or H, ILM is ON 9.85V/0.3A	7 VCC 15 310kΩ F F F F F F F F F F F F F F F F F F F

Timing Chart



HZIP15 Heat sink attachment

Heat sinks are used to lower the semiconductor device junction temperature by leading the head generated by the device to the outer environment and dissipating that heat.

a. Unless otherwise specified, for power ICs with tabs and power ICs with attached heat sinks, solder must not be applied to the heat sink or tabs.

b. Heat sink attachment

- Use flat-head screws to attach heat sinks.
- Use also washer to protect the package.
- Use tightening torques in the ranges 39-59Ncm(4-6kgcm).
- If tapping screws are used, do not use screws with a diameter larger than the holes in the semiconductor device itself.
- Do not make gap, dust, or other contaminants to get between the semiconductor device and the tab or heat sink.
- Take care a position of via hole.
- Do not allow dirt, dust, or other contaminants to get between the semiconductor device and the tab or heat sink.
- Verify that there are no press burrs or screw-hole burrs on the heat sink.
- Warping in heat sinks and printed circuit boards must be no more than 0.05 mm between screw holes, for either concave or convex warping.
- Twisting must be limited to under 0.05mm.
- Heat sink and semiconductor device are mounted in parallel.
 Take care of electric or compressed air drivers
- The speed of these torque wrenches should never exceed 700 rpm, and should typically be about 400 rpm.

Heat sink gap Via hole

mashine screv

c. Silicone grease

- Spread the silicone grease evenly when mounting heat sinks.
- Our company recommends YG-6260 (Momentive Performance Materials Japan LLC)

d. Mount

- First mount the heat sink on the semiconductor device, and then mount that assembly on the printed circuit board.
- When attaching a heat sink after mounting a semiconductor device into the printed circuit board, when tightening up a heat sink with the screw, the mechanical stress which is impossible to the semiconductor device and the pin doesn't hang.
- e. When mounting the semiconductor device to the heat sink using jigs, etc.,
 - Take care not to allow the device to ride onto the jig or positioning dowel.
 - Design the jig so that no unreasonable mechanical stress is applied to the semiconductor device.

f. Heat sink screw holes

- Be sure that chamfering and shear drop of heat sinks must not be larger than the diameter of screw head used.
- When using nuts, do not make the heat sink hole diameters larger than the diameter of the head of the screws used. A hole diameter about 15% larger than the diameter of the screw is desirable.
- When tap screws are used, be sure that the diameter of the holes in the heat sink are not too small. A diameter about 15% smaller than the diameter of the screw is desirable.
- g. There is a method to mount the semiconductor device to the heat sink by using a spring band. But this method is not recommended because of possible displacement due to fluctuation of the spring force with time or vibration.

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